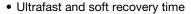


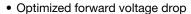
Ultrafast Rectifier, 8 A FRED Pt®

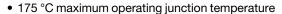


PRODUCT SUMMARY					
Package	TO-220AC				
I _{F(AV)}	8 A				
V_{R}	1200 V				
V _F at I _F at 125 °C	1.95 V				
t _{rr}	42 ns				
T _J max.	175 °C				
Diode variation	Single die				

FEATURES







Polyimide passivation

• Rugged design

Good thermal performance

AEC-Q101 qualified available

• Meets JESD 201 class 2 whisker test

 Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

Pb-free



ROHS COMPLIANT HALOGEN

FREE

DESCRIPTION / APPLICATIONS

Ultrafast recovery rectifiers designed with optimized forward voltage drop, ultrafast recovery time and soft recovery.

Polyimide passivated with a planar structure and platinum-doped lifetime control guarantee ruggedness, reliability and offer a solid value for efficiency and thermal performance.

These devices are intended for use in the boost stage in the AC/DC section of SMPS, high frequency output rectification of battery chargers, inverters for solar inverters or as freewheeling diodes in motor drives.

ABSOLUTE MAXIMUM RATINGS								
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS				
Repetitive peak reverse voltage	V_{RRM}		1200	V				
Average rectified forward current	I _{F(AV)}	T _C = 140 °C, D = 0.50	8					
Non repetitive peak surge current	I _{FSM}	$T_C = 25$ °C, $t_p = 10$ ms, sine wave	80	Α				
Repetitive peak forward current	I _{FM}		16					
Operating junction and storage temperature	T _J , T _{Stg}		-55 to +175	°C				

ELECTRICAL SPECIFICATIONS (T _J = 25 °C unless otherwise specified)							
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS	
Breakdown voltage, blocking voltage	V _{BR} , V _R	I _R = 200 μA	1200	-	-		
Forward voltage	V _F	I _F = 8 A	-	2.05	2.55	V	
		I _F = 8 A, T _J = 125 °C	-	1.95	2.37		
Deverage legisage everent	I _R	$V_R = V_R$ rated	-	-	55		
Reverse leakage current		$T_J = 125$ °C, $V_R = V_R$ rated	-	-	100	- μΑ	
Junction capacitance	C _T	V _R = 200 V	-	8	-	pF	
Series inductance	L _S	Measured lead to lead 5 mm from package body	-	8.0	-	nH	



DYNAMIC RECOVERY CHARACTERISTICS (T _J = 25 °C unless otherwise specified)								
PARAMETER	SYMBOL	TEST CONDITIONS		MIN.	TYP.	MAX.	UNITS	
		I _F = 1.0 A, dI _F /dt =	$I_F = 1.0 \text{ A}, dI_F/dt = 100 \text{ A/}\mu\text{s}, V_R = 30 \text{ V}$		42	-		
Reverse recovery time	t _{rr}	T _J = 25 °C	I _F = 8 A dI _F /dt = 100 A/μs V _R = 390 V	-	144	-	ns A	
		T _J = 125 °C		-	204	-		
Peak recovery current	I _{RRM}	T _J = 25 °C		-	5	-		
		T _J = 125 °C		-	7.2	-		
Reverse recovery charge	Q _{rr}	T _J = 25 °C		-	370	-	nC	
		T _J = 125 °C		=	745	-		

THERMAL - MECHANICAL SPECIFICATIONS							
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS	
Maximum junction and storage temperature range	T _J , T _{Stg}		-55	-	175	°C	
Thermal resistance, junction to case	R _{thJC}		-	1.25	1.5		
Thermal resistance, junction to ambient	R _{thJA}	Typical socket mount	-	54	60	°C/W	
Thermal resistance, case to heatsink	R _{thCS}	Mounting surface, flat, smooth, and greased	-	0.18	0.4		
Weight			-	0.2	-	g	
vveignt			-	0.07	-	OZ.	
Mounting torque			6.0 (5.0)	-	12 (10)	kgf · cm (lbf · in)	
Marking device		Case style: TO-220AC	8ETU12H				

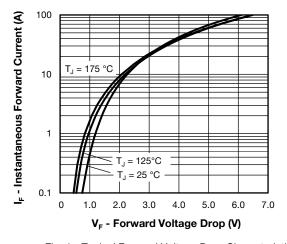


Fig. 1 - Typical Forward Voltage Drop Characteristics

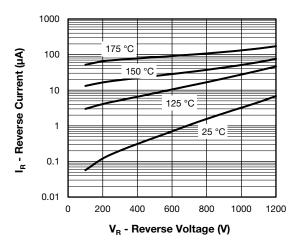


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage

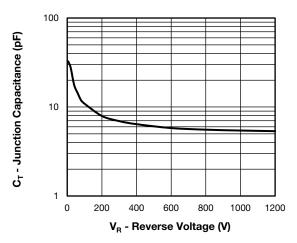


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

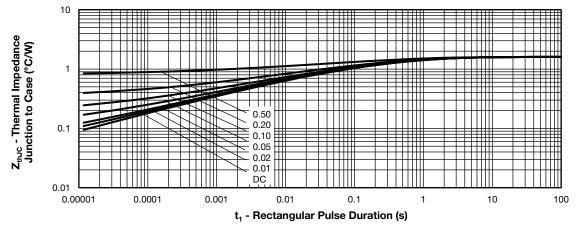


Fig. 4 - Maximum Thermal Impedance Z_{thJC} Characteristics

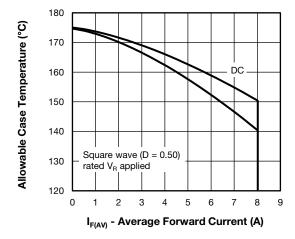


Fig. 5 - Maximum Allowable Case Temperature vs.
Average Forward Current

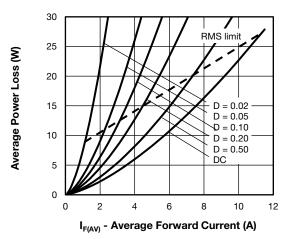


Fig. 6 - Forward Power Loss Characteristics

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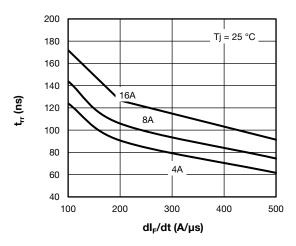


Fig. 7 - Typical Reverse Recovery Time vs. dl_F/dt

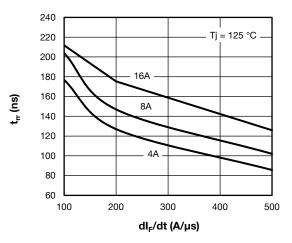


Fig. 8 - Typical Reverse Recovery Time vs. dl_F/dt

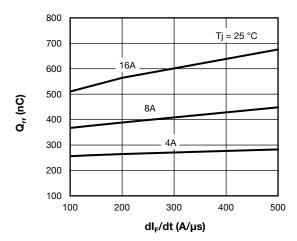


Fig. 9 - Typical Stored Charge vs. dl_F/dt

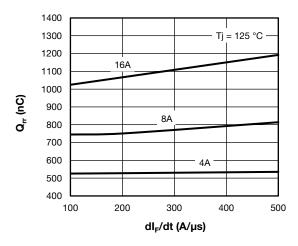


Fig. 10 - Typical Stored Charge vs. dl_F/dt

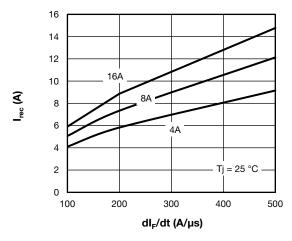


Fig. 11 - Typical Reverse Current vs. dI_F/dt

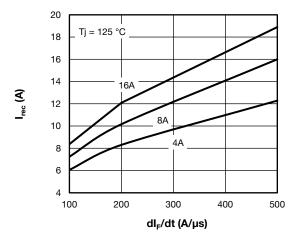
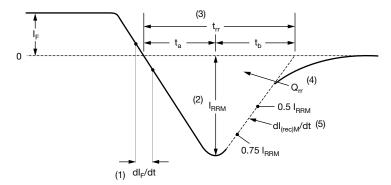


Fig. 12 - Typical Reverse Current vs. dl_F/dt



- (1) dl_F/dt rate of change of current through zero crossing
- (2) I_{RRM} peak reverse recovery current
- (3) t_{rr} reverse recovery time measured from zero crossing point of negative going I_F to point where a line passing through 0.75 I_{RRM} and 0.50 I_{RRM} extrapolated to zero current.
- (4) ${\rm Q_{rr}}$ area under curve defined by ${\rm t_{rr}}$ and ${\rm I_{RRM}}$

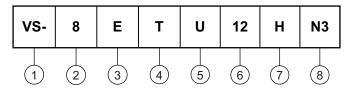
$$Q_{rr} = \frac{t_{rr} x I_{RRM}}{2}$$

(5) dl_{(rec)M}/dt - peak rate of change of current during t_b portion of t_{rr}

Fig. 13 - Reverse Recovery Waveform and Definitions

ORDERING INFORMATION TABLE

Device code



- 1 Vishay Semiconductors product
- **2** Current rating (8 = 8 A)
- Circuit configuration: E = single diode
- 4 Package:

T = TO-220

- 5 U = ultrafast recovery
- 6 Voltage rating (12 = 1200 V)
- 7 H = AEC-Q101 qualified
- 8 Environmental digit:

N3 = halogen-free, RoHS-compliant, and totally lead (Pb)-free

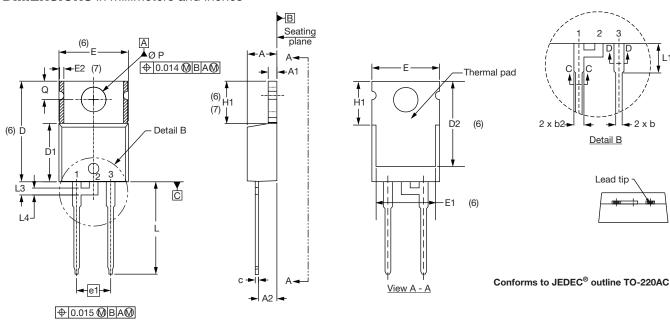
ORDERING INFORMATION (Example)						
PREFERRED P/N	QUANTITY PER T/R	MINIMUM ORDER QUANTITY	PACKAGING DESCRIPTION			
VS-8ETU12HN3	50	1000	Antistatic plastic tube			

LINKS TO RELATED DOCUMENTS					
Dimensions <u>www.vishay.com/doc?95221</u>					
Part marking information	www.vishay.com/doc?95068				



TO-220AC

DIMENSIONS in millimeters and inches



SYMBOL	MILLIN	IMETERS INCHES		HES	NOTES	
STIVIBUL	MIN.	MAX.	MIN.	MAX.	NOTES	
Α	4.25	4.65	0.167	0.183		
A1	1.14	1.40	0.045	0.055		
A2	2.56	2.92	0.101	0.115		
b	0.69	1.01	0.027	0.040		
b1	0.38	0.97	0.015	0.038	4	
b2	1.20	1.73	0.047	0.068		
b3	1.14	1.73	0.045	0.068	4	
С	0.36	0.61	0.014	0.024		
c1	0.36	0.56	0.014	0.022	4	
D	14.85	15.25	0.585	0.600	3	
D1	8.38	9.02	0.330	0.355		
D2	11.68	12.88	0.460	0.507	6	
E	10.11	10.51	0.398	0.414	3, 6	

MILLIMETERS		INCHES		NOTES
MIN.	MAX.	MIN.	MAX.	NOTES
6.86	8.89	0.270	0.350	6
-	0.76	-	0.030	7
4.88	5.28	0.192	0.208	
5.84	6.86	0.230	0.270	6, 7
13.52	14.02	0.532	0.552	
3.32	3.82	0.131	0.150	2
1.78	2.13	0.070	0.084	
0.76	1.27	0.030	0.050	2
3.54	3.73	0.139	0.147	
2.60	3.00	0.102	0.118	
	MIN. 6.86 - 4.88 5.84 13.52 3.32 1.78 0.76 3.54	MIN. MAX. 6.86 8.89 - 0.76 4.88 5.28 5.84 6.86 13.52 14.02 3.32 3.82 1.78 2.13 0.76 1.27 3.54 3.73	MIN. MAX. MIN. 6.86 8.89 0.270 - 0.76 - 4.88 5.28 0.192 5.84 6.86 0.230 13.52 14.02 0.532 3.32 3.82 0.131 1.78 2.13 0.070 0.76 1.27 0.030 3.54 3.73 0.139	MIN. MAX. MIN. MAX. 6.86 8.89 0.270 0.350 - 0.76 - 0.030 4.88 5.28 0.192 0.208 5.84 6.86 0.230 0.270 13.52 14.02 0.532 0.552 3.32 3.82 0.131 0.150 1.78 2.13 0.070 0.084 0.76 1.27 0.030 0.050 3.54 3.73 0.139 0.147

Notes

- (1) Dimensioning and tolerancing as per ASME Y14.5M-1994
- (2) Lead dimension and finish uncontrolled in L1
- (3) Dimension D, D1 and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outermost extremes of the plastic body
- (4) Dimension b1, b3 and c1 apply to base metal only
- (5) Controlling dimension: inches
- (6) Thermal pad contour optional within dimensions E, H1, D2 and E1
- (7) Dimension E2 x H1 define a zone where stamping and singulation irregularities are allowed
- (8) Outline conforms to JEDEC TO-220, D2 (minimum) where dimensions are derived from the actual package outline



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Vishay

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